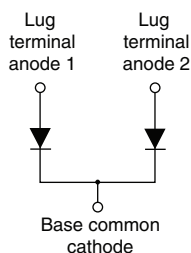


High Performance Schottky Rectifier, 200 A



TO-244



FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165 
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

PRODUCT SUMMARY

I _{F(AV)}	200 A
V _R	135 V, 150 V
Package	TO-244
Circuit	Two diodes common cathodes

DESCRIPTION

The VS-209CNQ center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	200	A
V _{RRM}	Range	135/150	V
I _{FSM}	t _p = 5 μs sine	10 000	A
V _F	100 A _{pk} , T _J = 125 °C (per leg)	0.71	V
T _J	Range	-55 to 175	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-209CNQ135PbF	VS-209CNQ150PbF	UNITS
Maximum DC reverse voltage	V _R	135	150	V
Maximum working peak reverse voltage	V _{RWM}			

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current per leg See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 131 °C, rectangular waveform	100	A
per device			200	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7	I _{FSM}	5 μs sine or 3 μs rect. pulse	10 000	
		10 ms sine or 6 ms rect. pulse	1200	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 5.5 A, L = 1 mH	15	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _R typical	1	A

**ELECTRICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	$V_{FM}^{(1)}$	100 A	1.06	V
		200 A	1.33	
		100 A	0.74	
		200 A	0.88	
Maximum reverse leakage current per leg See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^{\circ}\text{C}$	3	mA
		$T_J = 125\text{ }^{\circ}\text{C}$	45	
Maximum junction capacitance per leg	C_T	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^{\circ}\text{C}$	3000	pF
Typical series inductance per leg	L_S	From top of terminal hole to mounting plane	7.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R	10 000	V/ μ s

Note(1) Pulse width < 300 μ s, duty cycle < 2 %**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}	-55	-	175	$^{\circ}\text{C}$
Thermal resistance, junction to case	R_{thJC}	-	-	0.38	$^{\circ}\text{C/W}$
		-	-	0.19	
Thermal resistance, case to heatsink	R_{thCS}	-	0.10	-	
Weight		-	68	-	g
			2.4		oz.
Mounting torque		35.4 (4)	-	53.1 (6)	lbf · in (N · m)
Mounting torque center hole		30 (3.4)	-	40 (4.6)	
Terminal torque		30 (3.4)	-	44.2 (5)	
Vertical pull		-	-	80	lbf · in
2" lever pull		-	-	35	

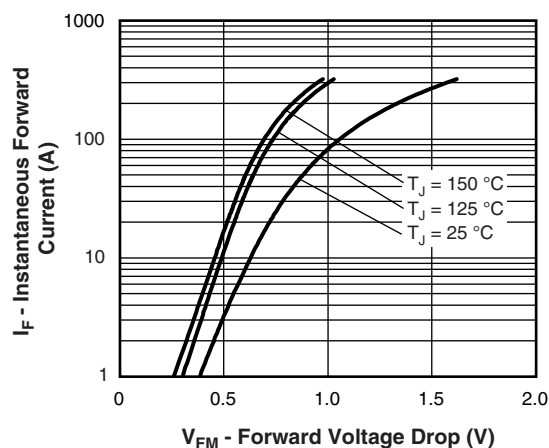


Fig. 1 - Maximum Forward Voltage Drop Characteristics

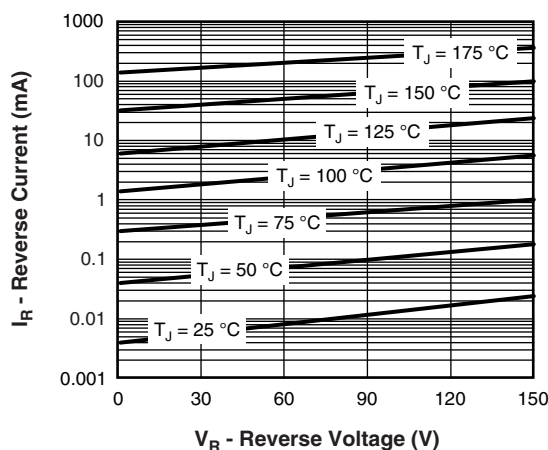


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

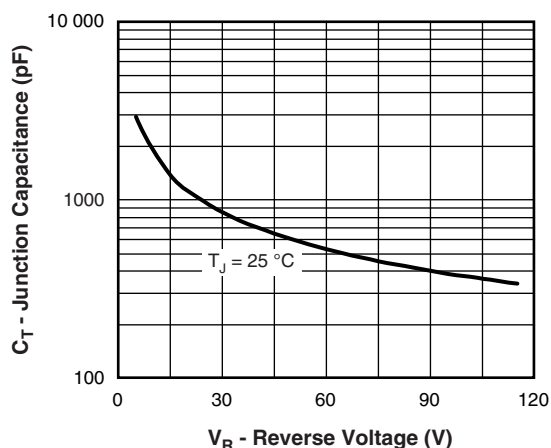


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

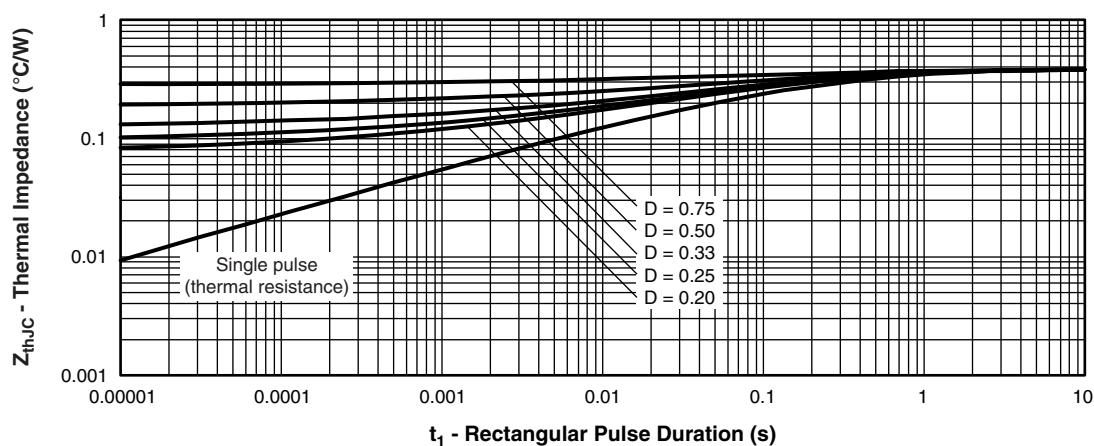
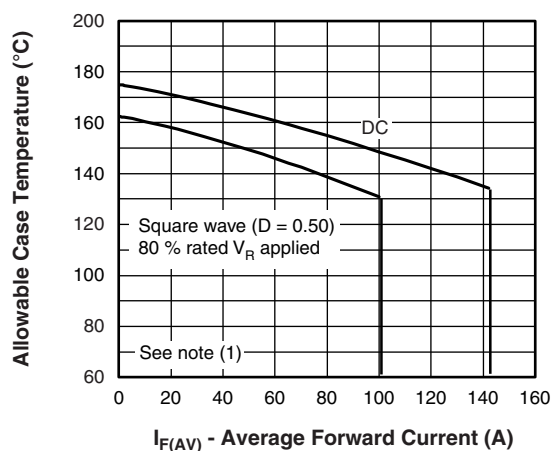

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

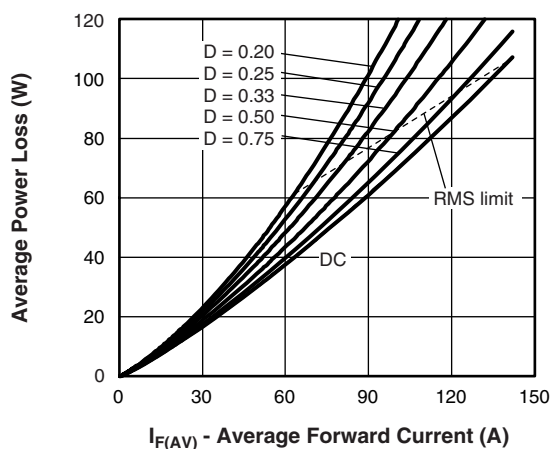


Fig. 6 - Forward Power Loss Characteristics

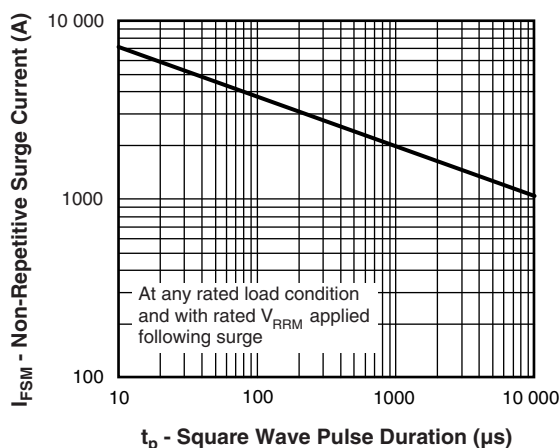


Fig. 7 - Maximum Non-Repetitive Surge Current

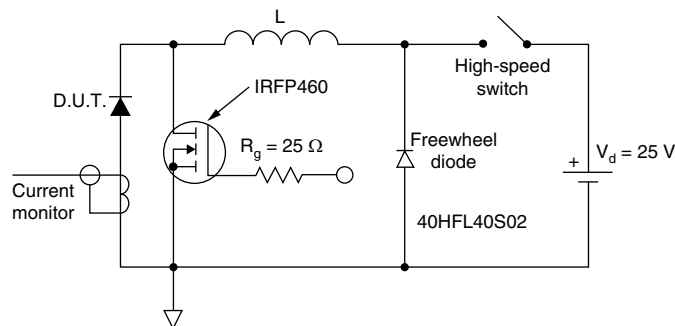


Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

ORDERING INFORMATION TABLE

Device code	VS-	20	9	C	N	Q	150	PbF
	1	2	3	4	5	6	7	8

1	-	Vishay Semiconductors product
2	-	Average current rating (x 10)
3	-	Product silicon identification
4	-	C = Circuit configuration
5	-	N = Not isolated
6	-	Q = Schottky rectifier diode
7	-	Voltage ratings
8	-	Lead (Pb)-free

135 = 135 V
150 = 150 V

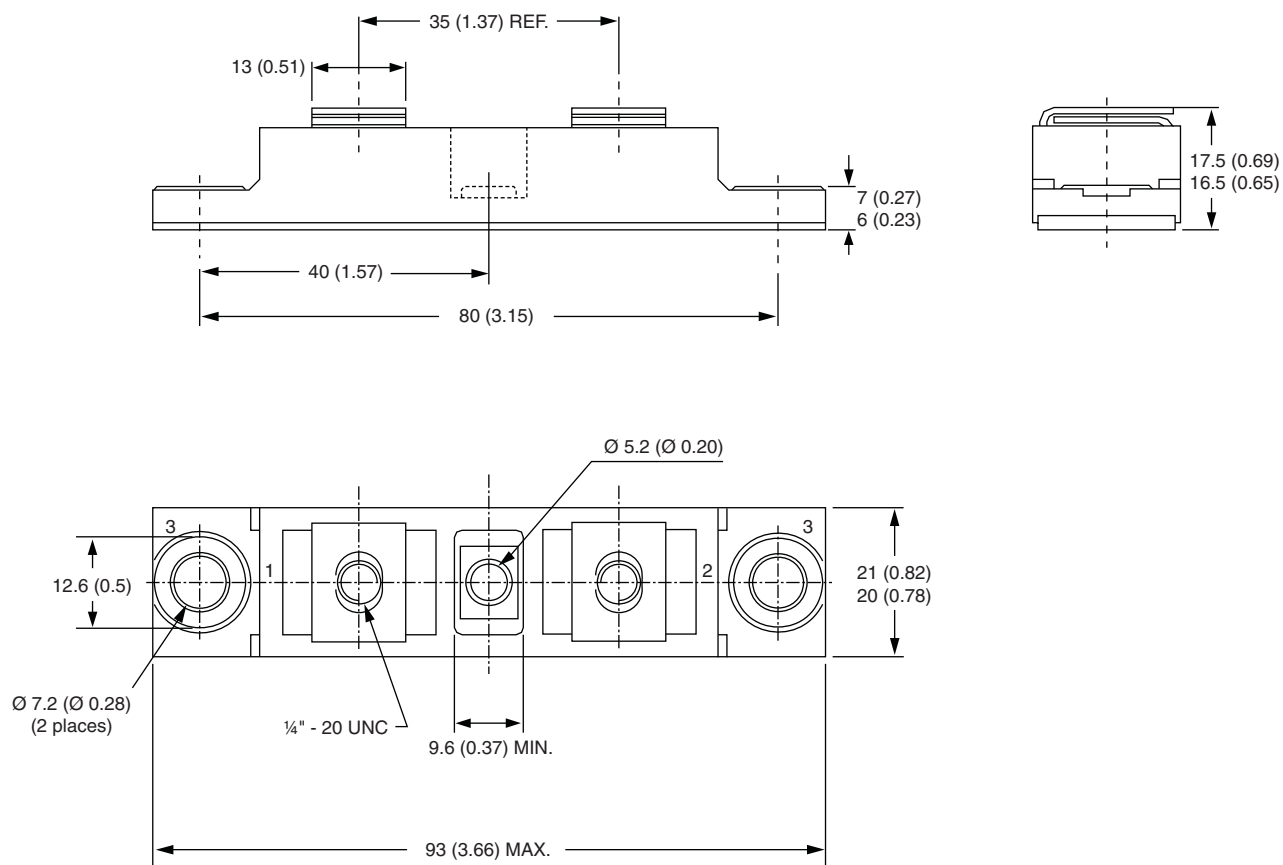
LINKS TO RELATED DOCUMENTS

Dimensions	www.vishay.com/doc?95021
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TO-244

DIMENSIONS in millimeters (inches)





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- Поставка сложных, дефицитных, либо снятых с производства позиций;
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- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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